

PQMD16

NPN/PNP resistor-equipped transistors;
R1 = 22 k Ω , R2 = 47 k Ω

15 April 2025

Product data sheet

1. General description

NPN/PNP double Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

4. Quick reference data

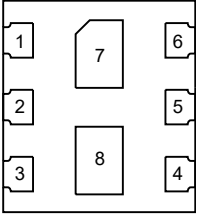
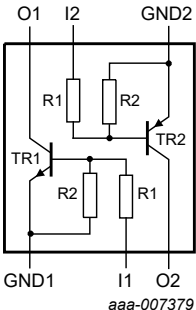
Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor; for the PNP transistor with negative polarity							
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
I _O	output current			-	-	100	mA
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	15.4	22	28.6	k Ω
R2/R1	bias resistor ratio		[1]	1.7	2.13	2.6	

[1] See section "Test information" for resistor calculation and test conditions.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 Transparent top view DFN1010B-6 (SOT1216)	 aaa-007379
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		
7	O1	output (collector) TR1		
8	O2	output (collector) TR2		

6. Ordering information

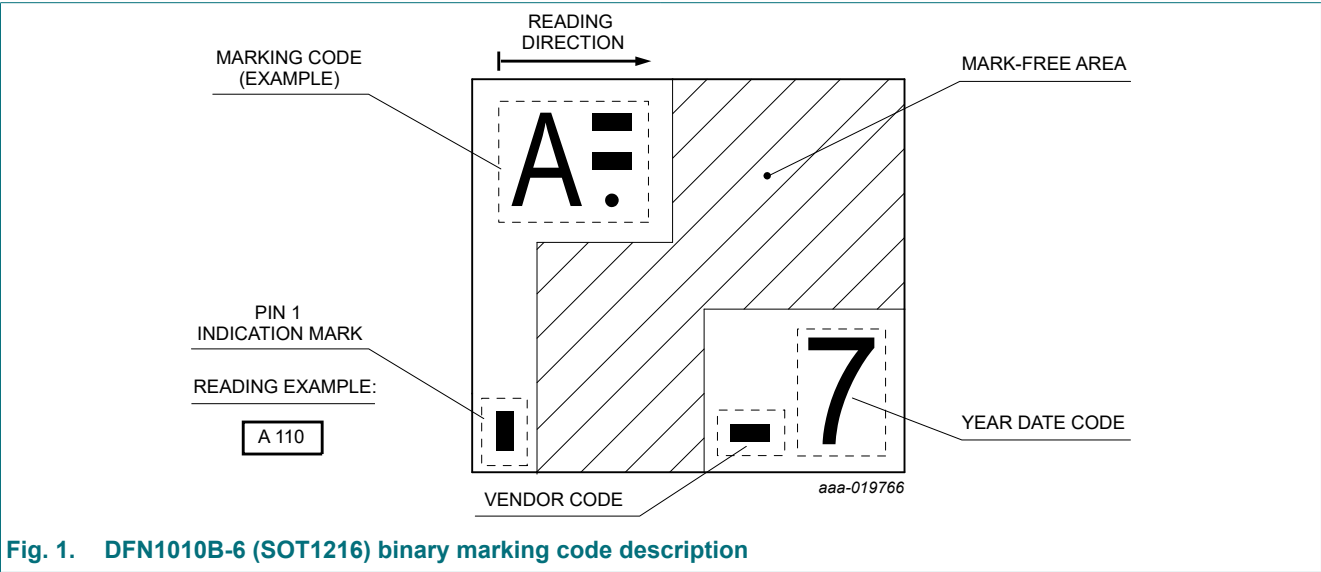
Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PQMD16	DFN1010B-6	plastic, leadless thermal enhanced ultra thin small outline package; 6 terminals; 0.35 mm pitch; 1.1 mm x 1 mm x 0.37 mm body	SOT1216

7. Marking

Table 4. Marking codes

Type number	Marking code
PQMD16	B 100

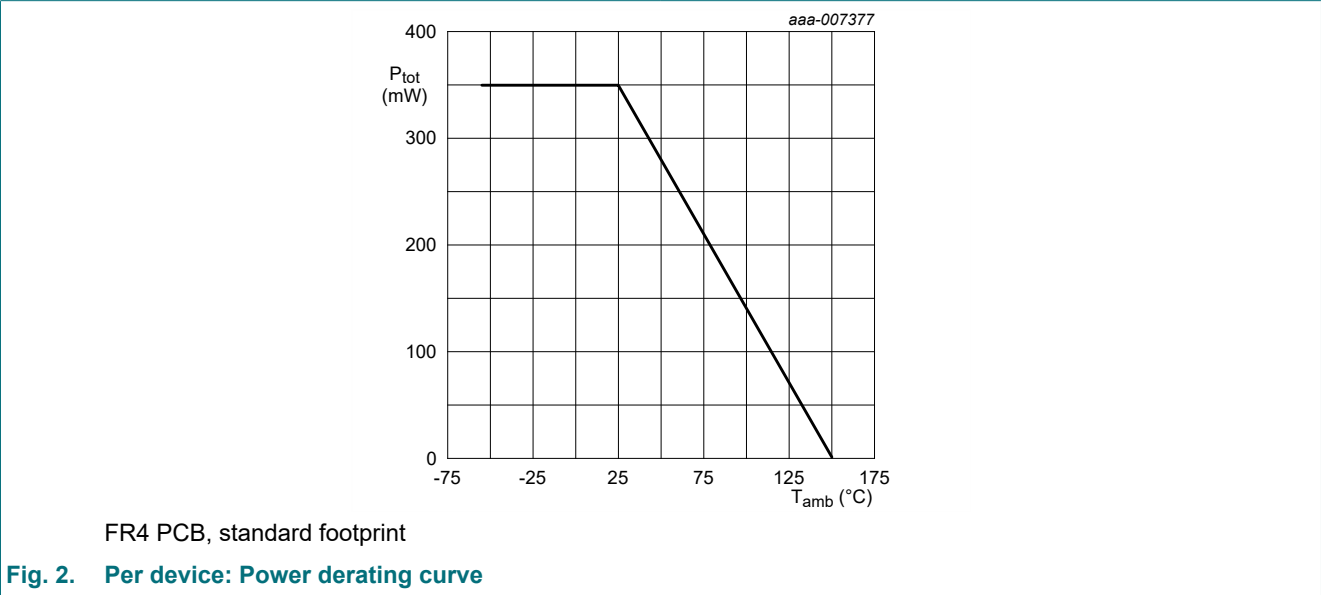


8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor; for the PNP transistor with negative polarity						
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	7	V
V _I	input voltage	TR1; positive		-	40	V
		TR1; negative		-	-7	V
		TR2; positive		-	7	V
		TR2; negative		-	-40	V
I _O	output current			-	100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	230	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

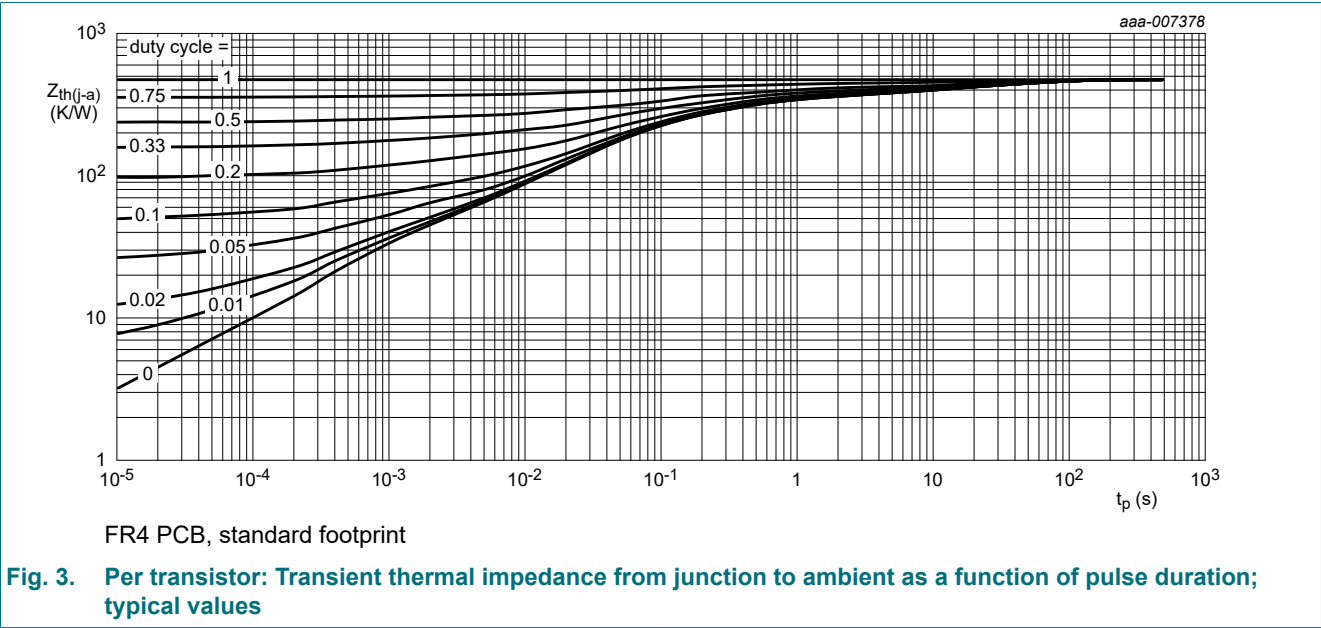


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

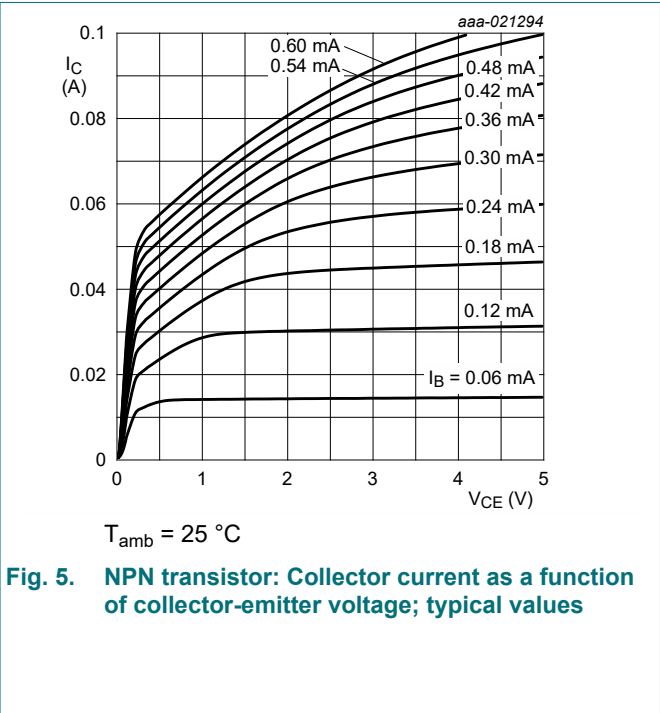
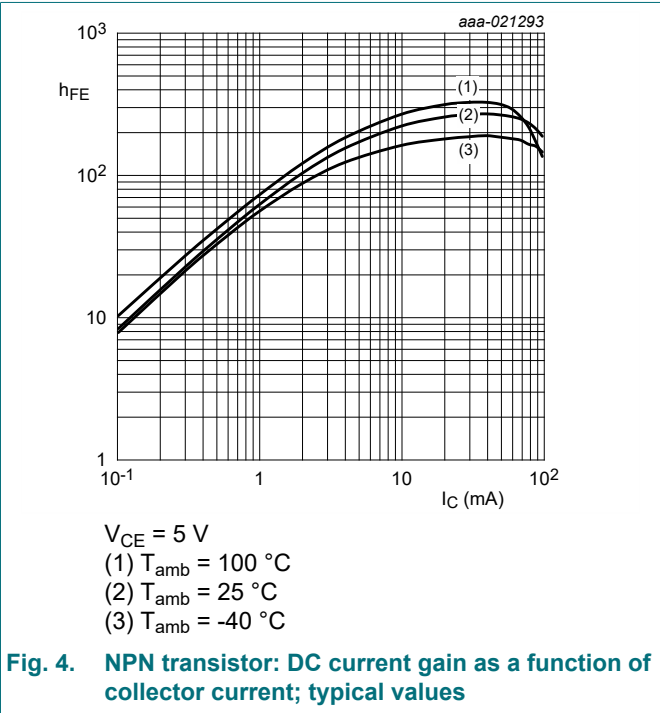


10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor; for the PNP transistor with negative polarity							
I_{CBO}	collector-base cut-off current	$V_{CB} = 50\text{ V}$; $I_E = 0\text{ A}$; $T_{amb} = 25\text{ °C}$		-	-	100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 30\text{ V}$; $I_B = 0\text{ A}$; $T_{amb} = 25\text{ °C}$		-	-	1	μA
		$V_{CE} = 30\text{ V}$; $I_B = 0\text{ A}$; $T_J = 150\text{ °C}$		-	-	50	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5\text{ V}$; $I_C = 0\text{ A}$; $T_{amb} = 25\text{ °C}$		-	-	120	μA
h_{FE}	DC current gain	$V_{CE} = 5\text{ V}$; $I_C = 5\text{ mA}$; $T_{amb} = 25\text{ °C}$		80	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10\text{ mA}$; $I_B = 0.5\text{ mA}$; $T_{amb} = 25\text{ °C}$		-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5\text{ V}$; $I_C = 100\text{ μA}$; $T_{amb} = 25\text{ °C}$		-	0.8	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3\text{ V}$; $I_C = 2\text{ mA}$; $T_{amb} = 25\text{ °C}$		2	1.1	-	V
R1	bias resistor 1 (input)	$T_{amb} = 25\text{ °C}$	[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	1.7	2.13	2.6	
C_c	collector capacitance	$V_{CB} = 10\text{ V}$; $I_E = 0\text{ A}$; $f = 1\text{ MHz}$; $T_{amb} = 25\text{ °C}$; TR1 (NPN)		-	-	2.5	pF
		$V_{CB} = -10\text{ V}$; $I_E = 0\text{ A}$; $f = 1\text{ MHz}$; $T_{amb} = 25\text{ °C}$; TR2 (PNP)		-	-	3	pF
f_T	transition frequency	$V_{CE} = 5\text{ V}$; $I_C = 10\text{ mA}$; $f = 100\text{ MHz}$; $T_{amb} = 25\text{ °C}$; TR1 (NPN)	[2]	-	230	-	MHz
		$V_{CE} = -5\text{ V}$; $I_C = -10\text{ mA}$; $f = 100\text{ MHz}$; $T_{amb} = 25\text{ °C}$; TR2 (PNP)	[2]	-	180	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
[2] Characteristics of built-in transistor



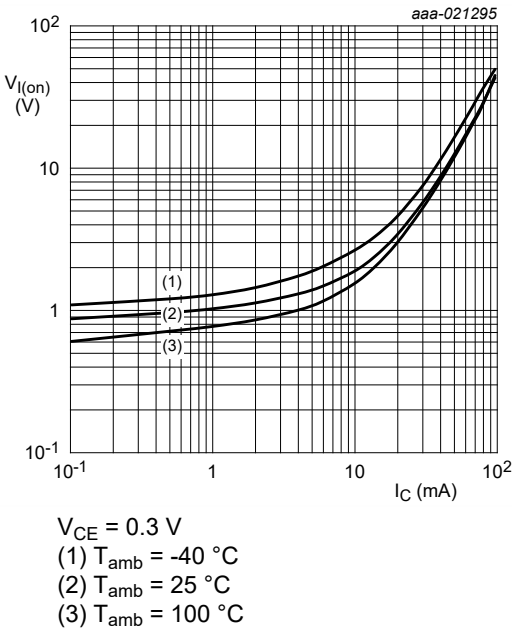


Fig. 6. NPN transistor: On-state input voltage as a function of collector current; typical values

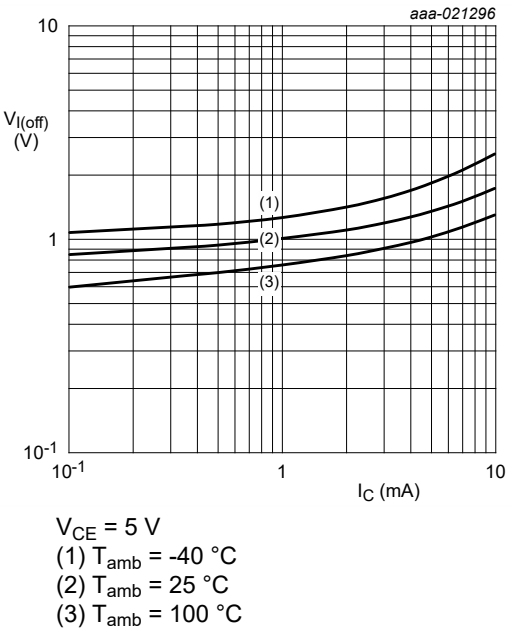


Fig. 7. NPN transistor: Off-state input voltage as a function of collector current; typical values

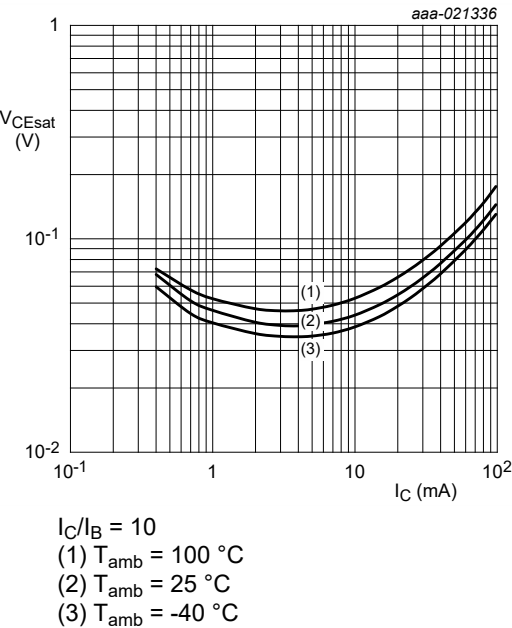


Fig. 8. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values

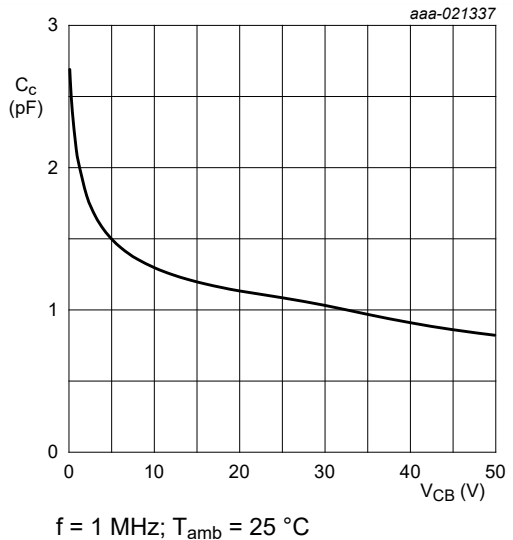


Fig. 9. NPN transistor: Collector capacitance as a function of collector-base voltage; typical values

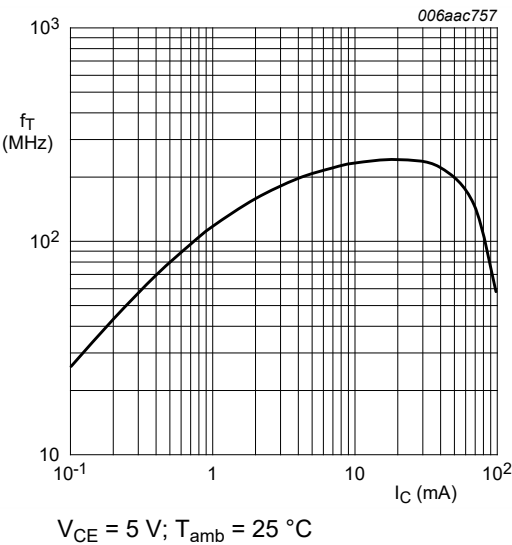


Fig. 10. NPN transistor: Transition frequency as a function of collector current; typical values of built-in transistor

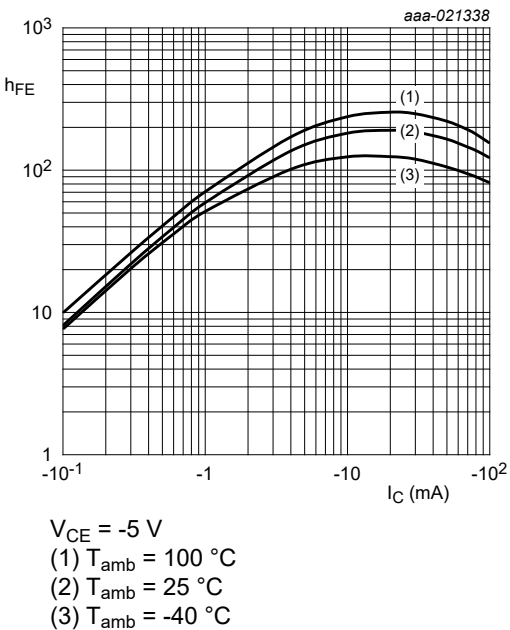


Fig. 11. PNP transistor: DC current gain as a function of collector current; typical values

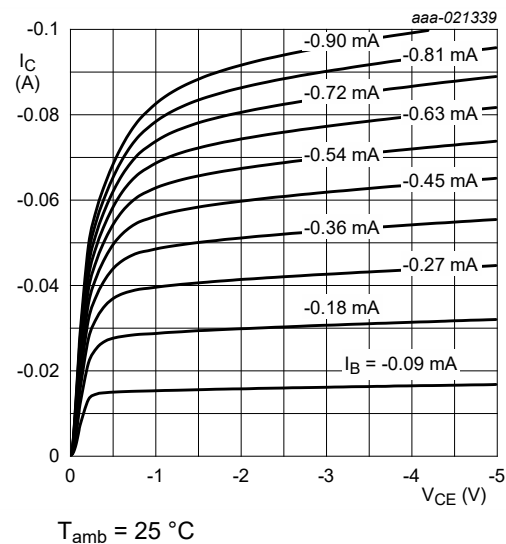


Fig. 12. PNP transistor: Collector current as a function of collector-emitter voltage; typical values

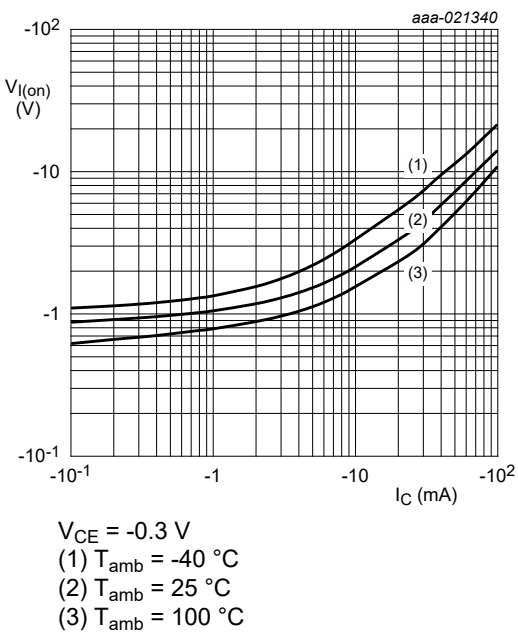


Fig. 13. PNP transistor: On-state input voltage as a function of collector current; typical values

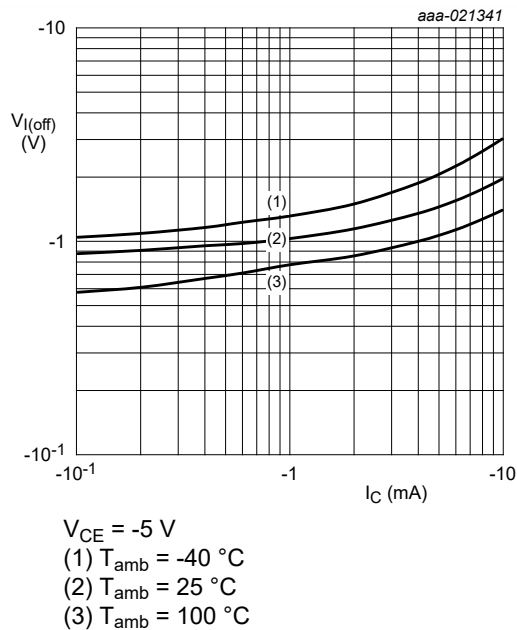


Fig. 14. PNP transistor: Off-state input voltage as a function of collector current; typical values

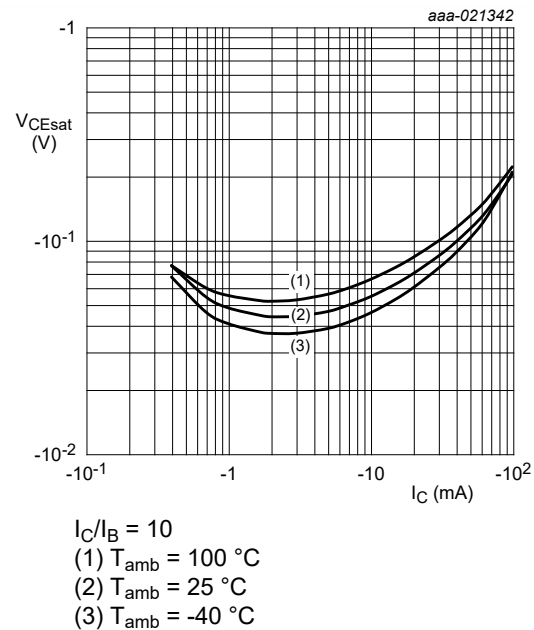


Fig. 15. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values

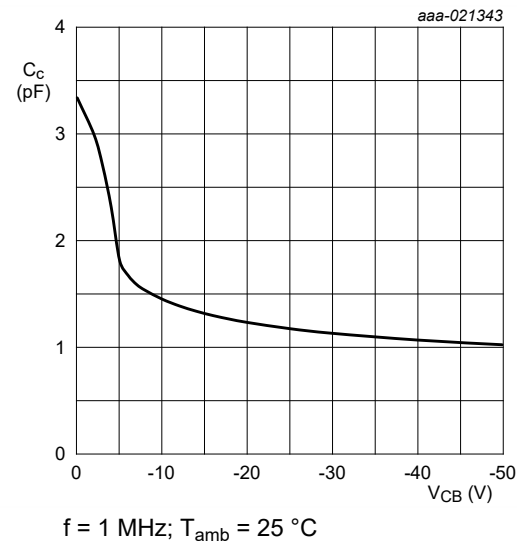


Fig. 16. PNP transistor: Collector capacitance as a function of collector-base voltage; typical values

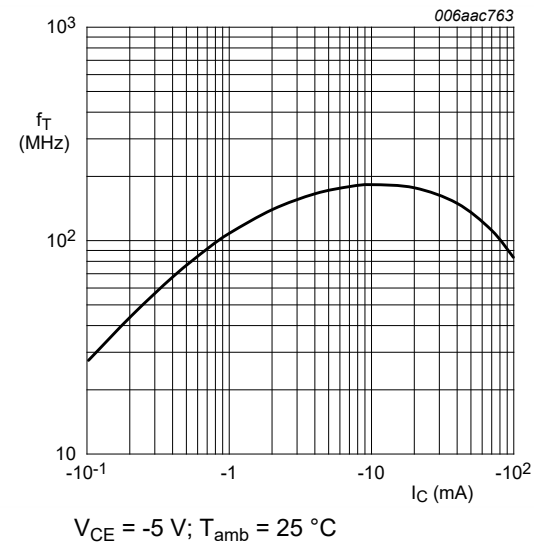


Fig. 17. PNP transistor: Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

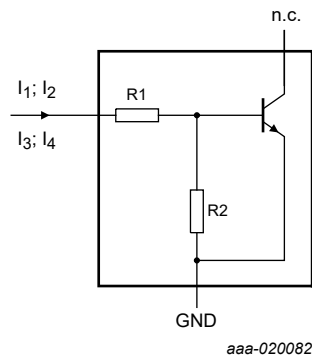


Fig. 18. NPN transistor: Resistor test circuit

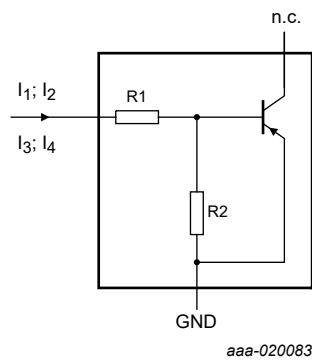


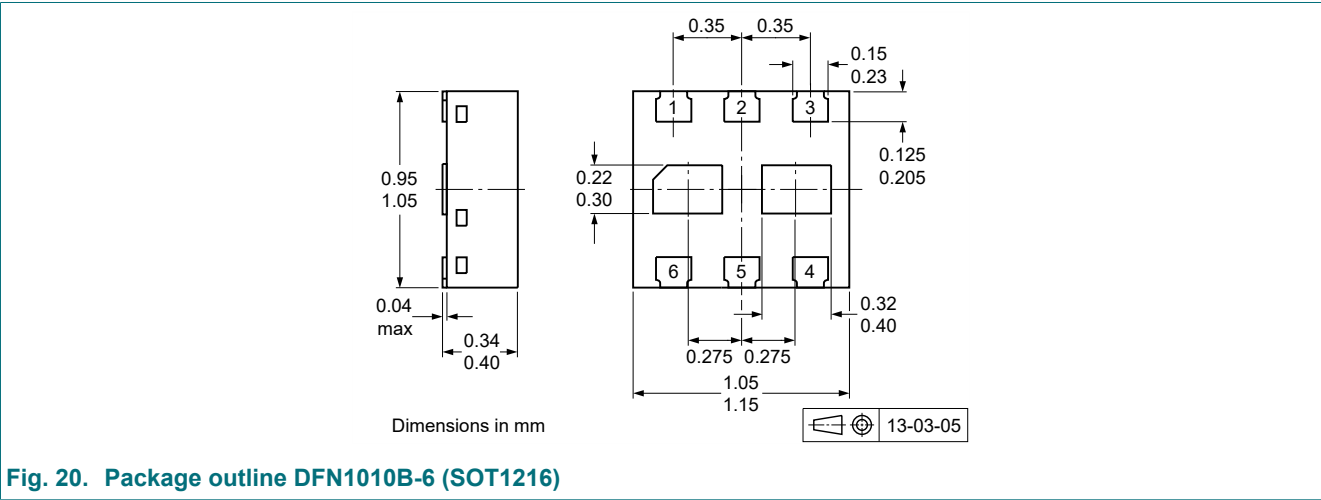
Fig. 19. PNP transistor: Resistor test circuit

Resistor test conditions

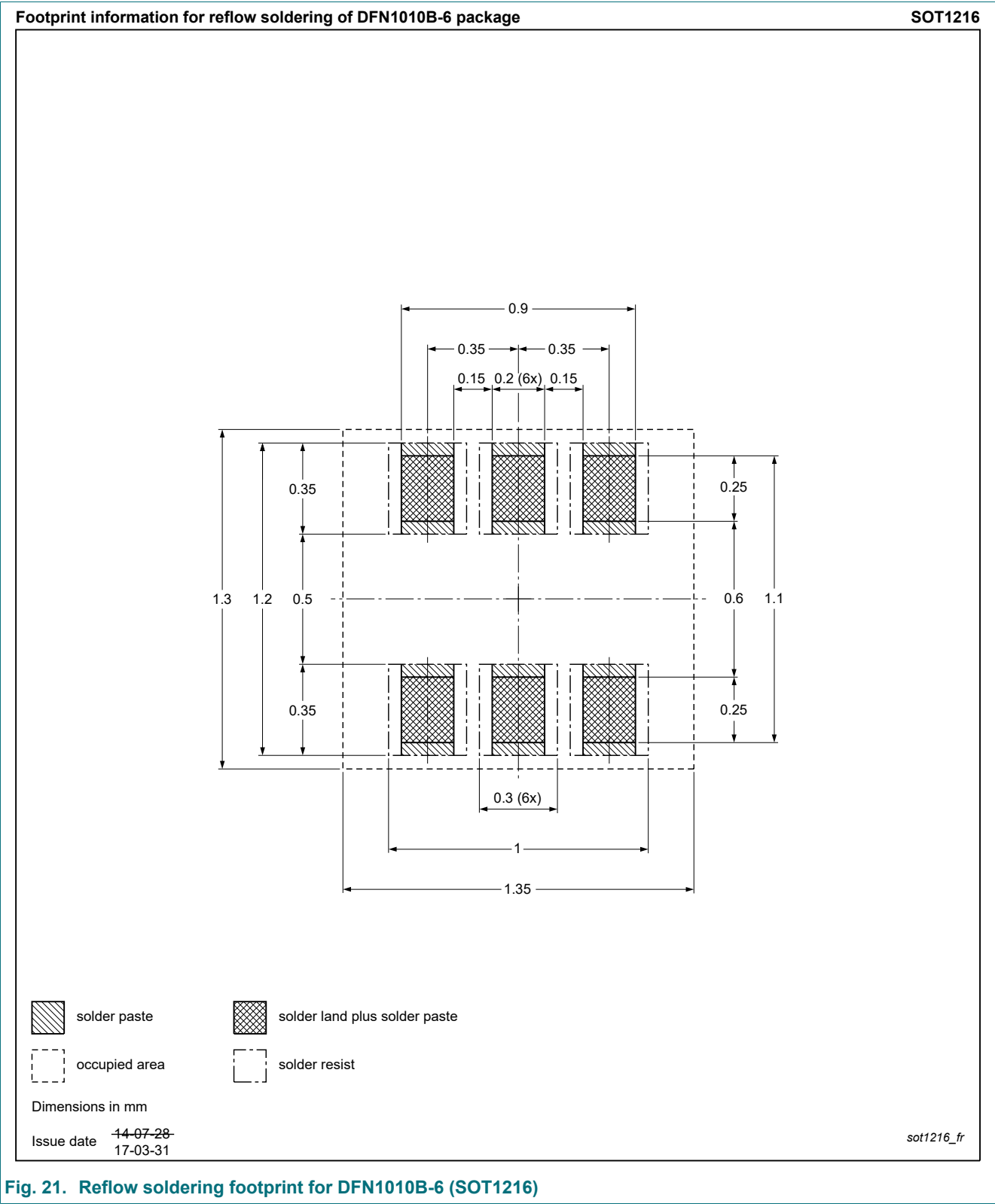
Table 8. Resistor test conditions
Per transistor; for the PNP transistor with negative polarity

R1 (kΩ)	R2 (kΩ)	Test conditions			
		I _{I1}	I _{I2}	I _{I3}	I _{I4}
22	47	90 μA	140 μA	-55 μA	-105 μA

12. Package outline



13. Soldering



14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PQMD16 v.2	20250415	Product data sheet	-	PQMD16 v.1
Modifications:	Soldering changed			
PQMD16 v.1	20151215	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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